Great Mixed Signal Technologies

GMT2607
LOW NOISE LDO FAMILY

DESCRIPTION

The GMT2607 family of extremely low dropout voltage regulators features very low ground current with a logic compatible ON/OFF switching input.

Designed especially for hand-held, battery-powered devices, this family includes a CMOS or TTL logic compatible enable/shutdown control input, and an internal under voltage monitor. When shutdown, power consumption drops nearly to zero. Dropout ground current is also minimized to prolong battery life.

The GMT2607 also features improved LINE and LOAD regulation characteristics for better system performance, and a Loop Stability characteristic that is INDEPENDENT of output Capacitor value as well as ESR.

Key options include an under-voltage monitor with an error flag output, a reference bypass pin to improve already low-noise performance, current limiting, and over-temperature shutdown.

The GMT2607 is available in adjustable output configuration, as well as, 2.5V, 2.7V, 3.0 V, 3.3 V, 3.6 V, 3.8 V, 4.0 V, and 4.75 V fixed voltage configurations. Full featured fixed and adjust-able output voltage versions, with the low noise bypass option, remote enable/shutdown, and error flag output are available in the 8-lead GMT Mini 8™, 8-lead MSOP. Limited feature options are available in ultra tiny GMT SOT packages for applications where“real estate” is at a premimum.

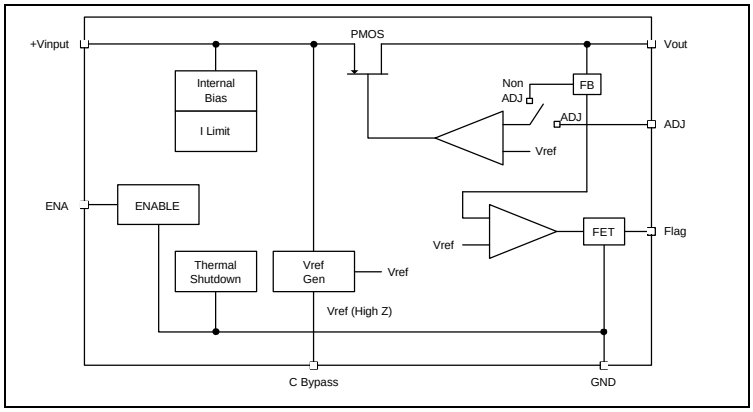
FEATURES

- Wide selection of output voltages: 2.5, 2.7, 3.0, 3.3, 3.6, 3.8, 4.0, & adjustable.
- Guaranteed 200 mA output drive.
- Current and thermal limiting.
- Zero OFF mode current.
- Logic-controlled electronic shutdown.
- High output voltage accuracy.
- Low 1.0 µA quiescent current.
- Low dropout voltage: 140 mV typical @ 100 mA,
- Extremely tight load and line regulation.
- Very low temperature coefficient.
- Error flag option indicates UV fault.
- Ultra low-noise output.
- Ground Current 1/10 of leading BiPolar LDO’s.

APPLICATIONS

- Cellular telephones.
- Laptop, notebook, and palmtop computers.
- Battery powered equipment.
- Bar code scanners.
- SMPS post-regulator/DC to DC modules.
- High efficiency linear power supplies.
- PCMCIA V_{CC} and V_{PP} regulation/switching.
- Consumer/personal electronics.

2607 BLOCK DIAGRAM



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ABSOLUTE MAXIMUM RATINGS
Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Electrical specifications do not apply when operating the device beyond its specified Recommended Operating Conditions.

Power Dissipation	Internally Limited
Junction Temperature	125°C
Lead Temperature (Soldering, 5 seconds)	260°C
Storage Temperature Range.....	-60°C to +150°C
Input Supply Voltage.....	-0.3 V to +7.0 V
ENABLE Input Voltage.....	-0.3 V to +7.0 V

RECOMMENDED OPERATING CONDITIONS

Input Voltage	2.5 V to 6.0 V
Operating Temperature Range, T_A	-40°C to +85°C
ENABLE Input Voltage.....	0.0 V to V_{CC}
SOT23-5 θ_{JA}	220°C/W (See Note 1)
MSOP-8 θ_{JA}	200°C/W (See Note 1)

Table 1: PACKAGE PIN ASSIGNMENTS

2607-xx (SOT23-5)	2607-Adj. (SOT23-5)	Pin Name	Pin Functions
1	1	V+	+ Supply
2	2	Gnd	Ground
3	3	V_{EN}	Enable
N/A	N/A	Flag	Error Flag Output
4	N/A	Byp	Bypass
N/A	4	Adj	V_{OUT} Adjust
5	5	V_{OUT}	Output

PIN DIAGRAMS

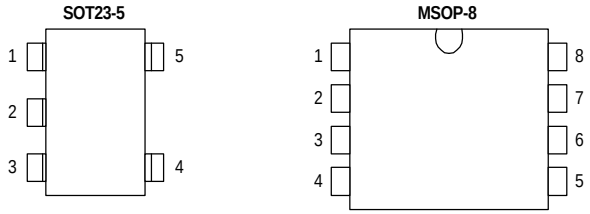

Table 2: PRODUCT FAMILY (GMT2607) SELECTION GUIDE

Part Number	Output Voltage	Output Current	Accuracy	Features	Operating Temp Range	Package
GMT2607-2.5S	2.5	200mA	3%	Enable/Shutdown, Bypass	-40°C to +85°C	SOT23-5
GMT2607-2.7S	2.7	200mA	3%	Enable/Shutdown, Bypass	-40°C to +85°C	SOT23-5
GMT2607-3.0S	3.0	200mA	3%	Enable/Shutdown, Bypass	-40°C to +85°C	SOT23-5
GMT2607-3.3S	3.3	200mA	3%	Enable/Shutdown, Bypass	-40°C to +85°C	SOT23-5
GMT2607-3.6S	3.6	200mA	3%	Enable/Shutdown, Bypass	-40°C to +85°C	SOT23-5
GMT2607-3.8S	3.8	200mA	3%	Enable/Shutdown, Bypass	-40°C to +85°C	SOT23-5
GMT2607-4.0S	4.0	200mA	3%	Enable/Shutdown, Bypass	-40°C to +85°C	SOT23-5
GMT2607-AdjS	Adjustable	200mA	3%	Enable/Shutdown, Adj.	-40°C to +85°C	SOT23-5

Table 3: ELECTRICAL CHARACTERISTICS - GMT2607-2.5, 2.7, 3.0, 3.3, 3.6, 3.8, 4.0, & Adj.

Limits are for T_A=25°C, and unless specified otherwise, limits which apply over the operating ambient temperature range of -40°C to +85°C will be determined by device characterization. Unless otherwise specified, V_{IN}=V_{OUT}+ 1.0 V, I_L = 1.0 mA, C_L= 1.0 uF and V_{EN}≥ 2.0 V.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
V_O	Output Voltage Accuracy	T_A = 25°C T_A = -40°C to +85°C	-3.0 -4.0		-3.0 -4.0	% %
$\Delta V_O/\Delta T$	Output Voltage Tempco	(Note 2)		6.0	140	ppm/°C
$\Delta V_O/V_O$	Line Regulation	V_{IN} =V_{OUT}+1.0 V to +6.0 V, T_A=25°C T_A =-40°C to +85°C			0.25 0.3	% %
$\Delta V_O/V_O$	Load Regulation (Note 3)	I_L = 0.1 mA to 150 mA, T_A=25°C T_A = -40°C to +85°C			0.3 0.5	% %
V_{IN}-V_O	Dropout Voltage (Note 4)	I_L =100 mA, T_A = 25°C I_L =100 mA, T_A = -40°C to + 85°C I_L =150 mA, T_A = 25°C I_L =150 mA, T_A = -40°C to + 85°C		140 165 	250 300 275 350	mV mV mV mV
I_Q	Quiescent Current	V_{EN}=≤0.4 V, T_A = -40°C to + 85°C			0.15	uA
I_{GND}	Ground Pin Current	V_{EN} =≤2.0 V, (active), I_L = 1.0 mA T_A = +25°C T_A = -40°C to + 85°C			 210 257	 uA uA
I_{GND}@V_{DO}	Ground Pin Current @ Dropout	V_{IN} = V_{OUT} -0.5 V T_A = 25°C T_A = -40°C to + 85°C			 700 943	 uA uA

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Symbol	Parameter	Conditions	Min	Typ	Max	Units
PSRR	Ripple Rejection	f = 100 Hz, I_L = 100 uA		49.5		dB
I_{LIMIT}	Current Limit	V_{OUT} = 0.0 V T_A = +25°C T_A = -40°C to + 85°C		0.5 0.5	1.0 1.5	A A
$\Delta V_O/\Delta P_D$	Thermal Regulation (Note 5)	I_L = 200 mA @ V_{IN}=+6.0 V 10 mS Pulse		0.05	0.1	%/W
V_{IL} V_{IH}	Input Voltage Logic Low Logic High	Regulator Shutdown Regulator Enabled	2.0		0.4	V V
I_{IL} I_{IL} I_{IH} I_{IH}	Control Input Current Logic Low Logic Low Logic High Logic High	$V_{IL}\leq$0.4 V $V_{IL}\leq$0.18 V, -40°C$\leq$+$T_A\leq$+85°C $V_{IH}\geq$2.0 V $V_{IH}\geq$2.0 V, -40°C$\leq$+$T_A\leq$+85°C			-1.0 -2.0 1.0 2.0	uA uA uA uA
e_{no}	Output Voltage Noise	C_{byp} = 470 pF		250		nV/$\sqrt{Hz}$

Table 4: ELECTRICAL CHARACTERISTICS - GMT2606-2.5, 2.7, 3.0, 3.3, 3.6, 3.8, 4.0, & Adj.

Limits are for T_A=25°C, and unless specified otherwise, limits which apply over the operating ambient temperature range of -40°C to +85°C will be determined by device characterization. Unless otherwise specified, V_{IN}=V_{OUT}+ 1.0 V, I_L = 1.0 mA, C_L= 1.0 uF and $V_{EN}\geq$ 2.0 V.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
V_O	Output Voltage Accuracy	T_A = 25°C T_A = -40°C to +85°C	-3.0 -4.0		+3.0 +4.0	% %
$\Delta V_O/\Delta T$	Output Voltage Tempco	(Note 2)		6	140	ppm/°C
$\Delta V_O/V_O$	Line Regulation	V_{IN} = V_{OUT}+1.0 V to +6.0 V, T_A= 25°C T_A=-40°C to +85°C			0.25 0.3	% %
$\Delta V_O/V_O$	Load Regulation (Note 3)	I_L= 0.1 mA to 150 mA, T_A=25°C T_A=-40°C to +85°C			0.3 0.5	% %
V_{IN}-V_O	Dropout Voltage (Note 4)	I_L=100 mA, T_A = 25°C I_L=100 mA, T_A = -40°C to +85°C I_L=150 mA, T_A = 25°C I_L=150 mA, T_A = -40°C to +85°C		140 165 	250 300 275 350	mV mV mV mV
I_Q	Quiescent Current	$V_{EN}\leq$0.4 V, T_A = -40°C to +85°C			0.15	uA
I_{GND}	Ground Pin Current	$V_{EN}\geq$2.0 V (active), I_L = 1.0 mA T_A = +25°C T_A = -40°C to +85°C			 210 257	 uA uA
$I_{GND}@V_{DO}$	Ground Pin Current @ Dropout	V_{IN} = V_{OUT} -0.5 T_A = 25°C T_A = -40°C to +85°C			 700 943	 uA uA
PSRR	Ripple Rejection	f=100 Hz, I_L = 100 uA		49.5		dB

Symbol	Parameter	Conditions	Min	Typ	Max	Units
I_{LIMIT}	Current Limit	V_{OUT}= 0.0 V T_A = 25°C T_A = -40°C to +85°C	 330 260		 350 450	 mA mA
$\Delta V_O/\Delta P_D$	Thermal Regulation (Note 6)	I_L=200 mA @ V_{IN}=+6.0 V 10 mS Pulse		0.05	0.1	%/W
V_{IL} V_{IH}	Input Voltage Logic Low Logic High	 Regulator Shutdown Regulator Enabled	 2.0		0.4	 V V
I_{IL} I_{IL} I_{IH} I_{IH}	Control Input Current Logic Low Logic Low Logic High Logic High	 $V_{IL}\leq$0.4 V $V_{IL}\leq$0.18 V, -40°C$\leq$+$T_A\leq$+85°C $V_{IH}\geq$2.0 V $V_{IH}\geq$2.0 V, -40°C$\leq$+$T_A\leq$+85°C			 -1.0 -2.0 1.0 2.0	 uA uA uA uA
V_{ERR}	Flag Threshold	Under voltage (below nomonal)			5.0	%
e_{no}	Output Voltage Noise	C_{byp}=470 pF		250		nV/√Hz
VOL	Output logic low voltage	IL = 1.0 mA, under-voltage condition			0.4	V
I_{FL}	Flag leakage current	Flag off, 0.0 V $\leq$ V_{FLAG} $\leq$ 6.0 V	-1		+1	uA

Table 5: ELECTRICAL CHARACTERISTICS - GMT2608-2.5, 2.7, 3.0, 3.3, 3.6, 3.8, 4.0, & Adj

Limits are for T_A=25°C, and unless specified otherwise, limits which apply over the operating ambient temperature range of -40°C to +85°C will be determined by device characterization. Unless otherwise specified, V_{IN}=V_{OUT}+ 1.0 V, I_L = 1.0 mA, C_L= 1.0 uF and $V_{EN}\geq$ 2.0 V.

Symbol	Parameter	Conditions	Min	Typ	Max	Units
V_O	Output Voltage Accuracy	T_A = 25°C T_A = -40°C to +85°C	-3.0 -4.0		+3.0 +4.0	% %
$\Delta V_O/\Delta T$	Output Voltage Tempco	(Note 2)		6	140	ppm/°C
$\Delta V_O/V_O$	Line Regulation	V_{IN} = V_{OUT}+1.0 V to +6.0 V, T_A=25°C T_A=-40°C to +85°C			0.25 0.3	% %
$\Delta V_O/V_O$	Load Regulation (Note 3)	I_L= 0.1 mA to 150 mA, T_A = 25°C T_A=-40°C to +85°C			0.3 0.5	% %
V_{IN}-V_O	Dropout Voltage (Note 4)	I_L=100 mA, T_A = 25°C I_L=100 mA, T_A = -40°C to +85°C I_L=150 mA, T_A = 25°C I_L=150 mA, T_A = -40°C to +85°C		140 165	250 300 275 350	mV mV mV mV
I_Q	Quiescent Current	V_{EN}=$\leq$0.4 V, T_A = -40°C to +85°C			0.15	uA
I_{GND}	Ground Pin Current	V_{EN}=$\geq$2.0 V (active), I_L = 1.0 mA T_A = +25°C T_A = -40°C to +85°C			 210 257	 uA uA
I_{GND}@V_{DO}	Ground Pin Current @ Dropout	V_{IN} = V_{OUT} -0.5 V T_A = 25°C T_A = -40°C to +85°C			 700 943	 uA uA
PSRR	Ripple Rejection	f=100 Hz, I_L = 100 uA		49.5		dB

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Symbol	Parameter	Conditions	Min	Typ	Max	Units
I_{LIMIT}	Current Limit	V_{OUT}= 0.0 V T_A = 25°C T_A = -40°C to +85°C	 330 260		 350 450	 mA mA
$\Delta V_O/\Delta P_D$	Thermal Regulation (Note 5)	I_L=200 mA @ V_{IN}=+6.0 V 10 mS Pulse		0.05	0.1	%
 V_{IL} V_{IH}	Input Voltage Logic Low Logic High	 Regulator Shutdown Regulator Enabled	 2.0		0.4	 V V
 I_{IL} I_{IL} I_{IH} I_{IH}	Control Input Current Logic Low Logic Low Logic High Logic High	 $V_{IL}\leq$0.4 V $V_{IL}\leq$0.18 V, -40°C$\leq$+$T_A\leq$+85°C $V_{IH}\geq$2.0 V $V_{IH}\geq$2.0 V, -40°C$\leq$+$T_A\leq$+85°C			 -1.0 -2.0 1.0 2.0	 uA uA uA uA
e_{no}	Output Voltage Noise	C_{byp}=470 pF		250		nV/√Hz

SPECIFICATION NOTES

Note 1: The maximum power dissipation is a function of the maximum junction temperature,$T_{J(max)}$, the junction-to-ambient thermal resistance, θ_{JA}, and the ambient temperature, T_A. The maximum allowable power dissipation at any ambient temperature is calculated using: $P_{D(max)} = (T_{J(max)} - T_A)\ \theta_{JA}$. Exceeding the maximum allowable power dissipation will result in excessive die temperature, and the device will go into thermal shutdown.
Note 2: Output voltage temperature coefficient is defined as the worst case voltage change divided by the total temperature range.
Note 3: Regulation is measured at constant junction temperature using low duty cycle pulse testing.
Note 4: Dropout voltage is defined as the input to output differential at which the output voltage drops 2% below its nominal value measured at 1.0 V differential.
Note 5: Thermal regulation is defined as the change in output voltage at a time "t" after a change in power dissipation is applied, excluding load or line regulation effects.

APPLICATIONS INFORMATION

General Device Description. The GMT2607 family of LDO regulators represent a new approach to LDO design. These devices offer all of the CMOS advantages of low current consumption, low forward drop and efficiency, plus added enhancements that are unique in the industry.

For example, the stability of the 2607 LDO family is INDEPENDENT of the output capacitor ESR, as well as the actual capacitance value. Not only does that mean no more struggling with marginal stability over operational extremes, but smaller, cheaper Cout values for most general applications. The input capacitor can typically assume a value of between 0.1 and 1.0 for most applications. Line and Load rejection have also been dramatically improved at high frequencies, which is a significant advantage in many of today's products that have noisy, switched-mode environments.

Input Capacitor. Good design practice dictates that a 0.1 to 1.0 uFd capacitor be placed from the GMT2607 input directly to GND, close to the actual package. Long trace runs leading to the LDO may require larger values to keep the ripple at acceptable levels.

Output Capacitor. Because the GMT2607 family does not depend on either ESR or capacitance value for stability, an inexpensive ceramic capacitor may typically be used for Cout; 1.0 uFd should be adequate for many applications. The actual determination is driven by what level of ripple is desired for a given load.

Reference Bypass Capacitor - BYP (reference bypass) is connected to the internal voltage reference. A 470 pF capacitor (C_{BYP}) connected from BYP to GND quiets this reference, providing a significant reduction in output noise. The start-up speed of the GMT2607 is inversely proportional to the size of the reference bypass capacitor. Applications requiring a slow ramp-up of output voltage should consider larger values of C_{BYP}. Conversely, if rapid turn-on is required, consider omitting C_{BYP}. If output noise is not a major concern, omit C_{BYP} and leave BYP open.

SELECTING THE ADJUSTABLE VERSION DIVIDER RESISTORS

When using the adjustable version, the external divider network must be selected to obtain the desired Vout. The first constraint on the divider network is the current draw, which is nominally set at 8.0 uA:

[Vout/ R divider] = 8.0 uA

One Resistor may now be selected, and the other solved for, knowing what Vout value is desired. The fundamental equation **Vo = Vref x (1 +(R1/R2))** is used; therefore, **R1 = R2 x {[Vo/Vref] - 1}**. Please see Table 6 on the following page.

THERMAL CONSIDERATIONS

The GMT2607 has been designed with internal over-current limiting, set at approximately 350 mA, as well as junction temperature detection, which limits TJ to approximately 150°C. In the event of a current overload, Vo shuts down when TJ reaches 150°C. The LDO will then turn back on as the junction cools. Even though the device is well protected, the designer must still properly manage the thermal environment in order to maximize efficiency and reduce stress. Maximum power dissipation is given by **Pd (max) = (Tjmax-TA)/ R θJA**. Where Tjmax is maximum allowable junction temperature, TA is the ambient temperature

RθJA is the package thermal coefficient. These numbers are derived under specific, controlled test conditions. Actual thermal performance ultimately depends on the application. Each individual board design must be carefully evaluated over full temperature and operational extremes. Please refer to the package data section for thermal coefficients.

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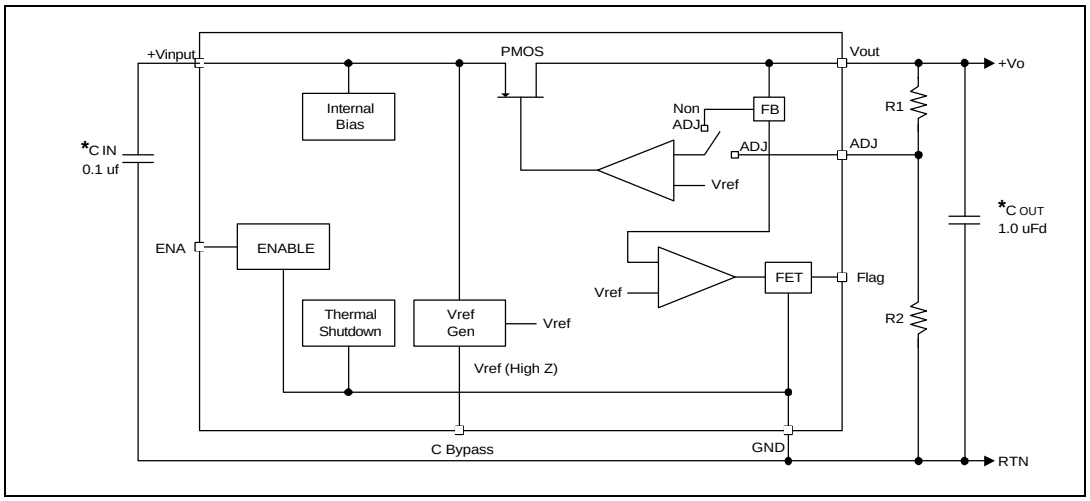
Table 6: 2607 ADJUSTABLE VERSION RESISTOR VALUES

OUTPUT VOLTAGE	DIVIDER VALUES; % (KOHM)	
	R1	R2
2.5	165 K	165 K
2.7	191 K	165 K
3.0	249 K	165 K
3.3	294 K	165 K
3.6	332 K	165 K
4.0	392 K	165 K
4.5	464 K	165 K
The Vout range of the 2607 series may be varied from approximately 1.2 V to 5.0 V. Resistor values may require adjustment to achieve desired set-points.		

2607 ADJUSTABLE REGULATOR APPLICATION DIAGRAM



*Suggested Capacitor Values Only

LIFE SUPPORT USAGE POLICY:

GMT's products are not authorized for use as critical components in life support devices or systems without the express written approval of the CEO of GMT. As used herein:
(a) Life support devices or systems are devices or systems which (1) are intended for surgical implant into the body, or (2) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
(b) A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system.

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